Approved for use through 07/31/2006. OMB 0651-0031

TDANOMITTAL		Application Number	10/581,622	
TRANSMITTAL	-	Filing Date	June 5, 2006	
FORM (to be used for all correspondence after initial filing)		First Named Inventor	David Thomas FORREST	
		Art Unit	1774	
		Examiner Name		
otal Number of Pages in This Submiss	ion	Attorney Docket Number	52993/326894	
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Document(s) Response to Missing Parts/ Incomplete Application				
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SIG	NATURE OF	APPLICANT, ATTORNEY, C	PR AGENT	
Firm or Individual name Bruce D. Gray, Ro	g. No. 35,799			
Signature M2				
Date 31 Oct	2006			
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APPLICANT:

David FORREST, et al.

SERIAL NO.:

10/581,622

Group Art Unit:

1774

FILED:

June 5, 2006

EXAMINER:

FOR:

FREE-STANDING SILICON CARBIDE ARTICLES FORMED BY CHEMICAL VAPOR DEPOSITION AND METHODS FOR THEIR MANUFACTURE

ATTORNEY DOCKET NO.: 52993/326894

DATE:

10/31/06

Mail Stop Amendment Commissioner for Patents P. O. Box 1450 Alexandria, Virginia 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

In accordance with Rules 56, 97 and 98 of the Rules of Practice in Patent Cases (37 C.F.R. §§ 1.56, 1.97, and 1.98), the publications listed on the modified Form PTO/SB/08 are cited for consideration by the Examiner. Copies of the non-U.S. patent documents and other literature are submitted with this paper.

Submission of the references provided in this Information Disclosure is not intended to constitute an admission that any reference referred to herein is prior art for this invention unless specially designated as such. Also, in accordance with 37 C.F.R. § 1.97(g), the filing of this Information Disclosure Statement shall not be construed to mean that a search has been made or that no other material information as defined in 37 C.F.R. § 1.56(a) exists.

U.S. Patent Application Serial No. 10/581,622

Filed: June 5, 2006

INFORMATION DISCLOSURE STATEMENT

This Information Disclosure Statement is being filed pursuant to 37 C.F.R. 1.97(b), before issuance of a first Office action on the merits. Applicant believes that no fee is due for submission and consideration of this paper. The Commissioner is authorized to charge any fees

associated with this filing or credit any overpayment to Deposit Account No. 11-0855.

Respectfully submitted,

Bruce D. Gray

Reg. No. 35,7992

KILPATRICK STOCKTON LLP Suite 2800, 1100 Peachtree Street Atlanta, Georgia 30309-4530 (404) 815-6218

PTO/SB/08A (10-01)

Van Zile, et al.Approved for use through 10/31/2002. OMB 0651-0031
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Complete if Known INFORMATION DISCLOSURE Application Number 10/581,622 Date Filed: June 5, 2006 STATEMENT BY APPLICANT First Named Inventor **David FORREST Group Art Unit** 1774 (use as many sheets as necessary) **Examiner Name** of 2 Attorney Docket Number 52993/326894 Sheet

			U.S. PA	TENT D	OCUM	ENTS		
Examine r Initials *	Cite No.1	Document Number Number - Kind Code ² (if known)	Publication Date MM-D/D-YYYY/		Name of Patentee or Applicant of Cited Document		Pages, Columns, Lines, Where Relevan Passages or Relevant Figures Appear	
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		Foreign Patent Docum		EIGN PAI	EN D	JCOMENTS	Pages, Columns,	
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		E P 1 127955 A1		08-29-	2001	Shipley Compan LLC	у	
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		WO 99/41773	:	08-19-	1999	Applied Materials Inc.	5,	

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Sheet

2

of 2 Application Number 10/581,622 Date Filed: June 5, 2006 **David FORREST** First Named Inventor Group Art Unit 1774 **Examiner Name** 52993/326894 Attorney Docket Number

	OTHER PRIOR ART NON PATENT LITERATURE DOCUMENTS				
Examiner Initials *	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T²		
		Collins, et al., 'Investigation of CVD β-SiC Surfaces Produced via a 'Novel' Surface Replication Process,' <i>Mat. Res. Soc. Symp. Proc.</i> , 168:193-198 (1990)			
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		Goela and Taylor, 'Chemical Vapor Deposition for Silicon Cladding on Advanced Ceramics,' J. Am. Ceram. Soc., 72(9):1747-1750 (1989)			
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		Qadri, et al., 'Characteristics of Plasma Processed SiC Nanocrystallites and Nanorods,' Applied Physics Letters, American Institute of Physics, 83(3):548-550 (July 21, 2003)			

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